

SQ7101/SQ7103 **Brief Datasheet V2.2**

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Name: SQ7101/SQ7103 Brief Datasheet Version: V2.2 No.: TDDS01-S7101-EN(B)

SQ7101/SQ7103, Secure ASIC, AES-128/AES-256, SHA-256, TRNG

Basic Information

Operating Voltage: 2.0V ~ 5.5V

Operating Temperature : -40°C ~ 85°C

Package Type



SOP8



Communication

SQ7101 support I2C interface (max. 400Kbps)

SQ7103 support SPI interface (max. 5MHz@MODE 0)

8-Lead DFN (3mm x 3mm)

- **High-Security Features**
 - AES-128/AES-256
 - SHA-256
 - True Random Number Generator (TRNG)
 - **Enclosure Intrusion Protection**
 - Simple/Differential Power Analysis (SPA/DPA)
 - Individual Internal Clock to Prevent Glitch Attack
 - 128-bit Unique ID
 - NIST CAVP Certification
- Support 16 keys with 128-bit or 8 keys with 256-bit
- 256 Bytes User Data
- 768 Bytes Small Zone
- 16 Monotonic Counters, Prevent replay attacks and man-in-the-middle attacks
- Low Power
 - Deep Sleep Current 250nA
- **Applications**
 - **Accessory Authentication**
 - System Anti-Clone
 - Security Smart Lock
 - Session Key Exchange
 - Chain of Trust

- **Device Authentication**
- Sensitive Data Protection and Encryption
- Firmware Protection

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1. Preface

SQ7101/SQ7103 is high-security, low-power Secure ASIC. This device offers TRNG (True Random Number Generator), Hardware Cryptography AES-128, AES-256, SHA-256 and Anti-Tamper function. The device can support 16 keys with 128-bit or 8 keys with 256-bit.

SQ7101/SQ7103 Secure ASIC is suitable for security application, such as Accessory Authentication, System Anti-Clone, Security Smart Lock, Critical Data Encryption, and so on.

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2. Pin Assignment/Description

2.1 SQ7101 Assignment/Description

PRODUCT: SQ7101SP008C00R

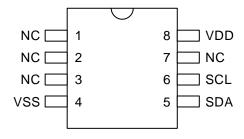


Figure 2-1 Pin Assignment of SQ7101 SQP8

PRODUCT: SQ7101N3008C00R

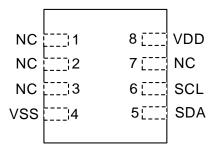


Figure 2-2 Pin Assignment of SQ7101 8-Lead DFN

Pin No.	Pin Name/Pin Option	I/O Type	Function Description
1	NC	-	No Connect
2	NC	-	No Connect
3	NC	-	No Connect
4	VSS	GND	Ground
5	SDA	I/O	SDA, I2C bus data input/output
6	SCL	1	SCL, I2C bus clock input/output
7	NC	-	No Connect
8	VDD	Power	VDD Power Supply

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2.2 SQ7103 Assignment/Description

PRODUCT: SQ7103SP008S00R

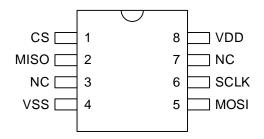


Figure 2-3 Pin Assignment of SQ7103 SOP8

PRODUCT: SQ7103N3008S00R

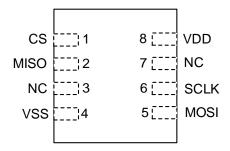
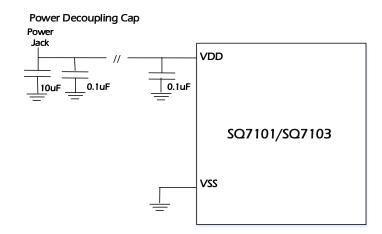


Figure 2-4 Pin Assignment of SQ7103 8-Lead-DFN

Pin No.	Pin Name/Pin Option	I/O Type	Function Description
1	CS	I	SPI, Chip Select
2	MISO	0	SPI, Master In Slave Out
3	NC	-	No Connect
4	VSS	GND	Ground
5	MOSI	I	SPI, Master Out Slave In
6	SCLK	I	SPI,SPI Clock
7	NC	-	No Connect
8	VDD	Power	VDD Power Supply

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The following is the recommended reference designs when using SQ7101/SQ7103 products. If the relevant pin are used, please refer to the corresponding suggestions:



Note: The 0.1uF near the IC (VDD) in the above figure should be as close to the IC as possible

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3. Electrical Characteristics

3.1 Absolute Maximum Ratings

The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded

 $(V_{SS} = 0V)$

Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V_{DD}		-0.3 to 6.0	V
Input Voltage	V _{IN}	All I/O pins	-0.3 to VDD+0.3V	V
Output Current (total)	l _{OL}	All I/O pins	50	mA
Storage Temperature	T _{STG}		-50 to 125	°C

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3.2 Operation Conditions

The following defines the electrical characteristics of the device when it is operated at voltage and temperature maximum/minimum values. Unless otherwise stated, the standard conditions were determined at "operating temperature 25 ° C and operating voltage VDD = 3.3 V".

3.2.1 Operation Conditions

Parameter	Symbol	Min.	Тур.	Max.	Unit
Operating Voltage	V_{DD}	2.0	3.3	5.5	V
Operating Temperature	Та	-40	25	85	°C

3.2.2 I/O Characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Low Voltage	V_{IL}		0		0.3 VDD	٧
Input High Voltage	V_{IH}		0.7 VDD		VDD	V
Output Low Voltage	V _{OL}	IOL= 3 mA	0		0.1 VDD	V
Output High Voltage	V _{OH}	IOH= -3 mA	0.9VDD		VDD	V

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3.3 DC Characteristics

Parameter	Symbol	Conditions	Mln	Тур	Max	Unit
Operation Mode	I _{DD_N1}	VDD=3.3V, Temp=25 °C		3		mA
Deep Sleep Mode	I _{DD_Ds}	VDD=3.3V, Temp=25 °C		250		nA

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3.4 Power-on Reset Characteristics

Ta=-40~85°C						
Symbol	Description	Mln	Тур	Max	Unit	
tPPW	Power-on reset minimum pulse width	1	-	-	ms	
tPWUP	Warming-up time after a reset is clear and device ready	-	4	-	ms	
tVDD	Power supply rise time	0.5		5	ms	

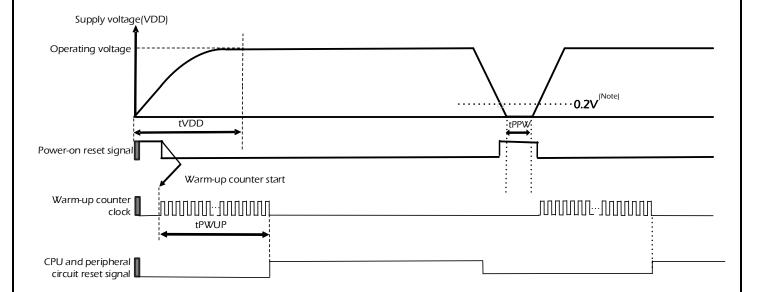


FIGURE 3- 1 OPERATION TIMING OF POWER-ON RESET

Note: In power-down process, the VDD must be less than 0.2V, then re-power-on to ensure the IC operating normal.

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3.5 BROR Characteristics

Ta=-40~85°C							
Parameter Symbol		Condition N		Тур	Max	Unit	
BROR detect voltage	VBROR Rising	VDD rise time and fall time > tVDD	1.95	2.0	2.05	V	
	VBROR Falling	(tVDD refer to CH3.4 Power-on- Reset Characteristics)	1.85	1.90	1.95	V	

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3.6 AC Characteristics

Parameter	Symbol	Mln	Тур	Max	Unit
User Data Write Cycle Time (Note)	Twc ₁	6.0	-	9.0	mS
128-bit/256-bit Key Write Time (Note)	Twc ₂	6.0		9.0	mS

Note: Writer time is including data update.

3.6.1 AC Parameters

Parameter	Symbol	Mln	Тур	Max	Unit
Power-Up Ready Time	T_{PU_RDY}		2800	9300	uS
Standby Time, Entering deep sleep mode	T _{STB}		55	90	uS
Wake-Up Ready Time, deep sleep mode	Tw _{Ds_RDY}		300	-	uS

Note: The Typ value is under operating temperature 25 ° C and the Sleep command changes this value.

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3.6.2 I2C Characteristics

Parameter	Symbol	Min	Max	Unit
Clock Frequency	f _{SCL}	0	400	kHz
Hold Time Repeated START Condition	t _{HD;STA}	0.6	-	us
Low Period of SCL Clock	t _{LOW}	1.3	-	us
High Period of SCL Clock	t _{HIGH}	0.6	-	us
Setup Time for a Repeated START Condition	t _{su;sta}	0.6	-	us
Data Hold Time	t _{HD;DAT}	0	0.8	us
Data Setup Time	t _{su;DAT}	0.1	-	us
Rise time of both SDA and SCL	t _r	20	300	ns
Fall Time of both SDA and SCL	t _f	20	300	ns
Setup Time of STOP Condition	t _{su;sto}	0.6	-	us
Bus Free Time between a STOP and START Condition	t _{BUF}	1.3	-	us
Capacitive Load for Each Bus line	Сь	-	400	pF

Note: Guaranteed by characteristic, not tested in production.

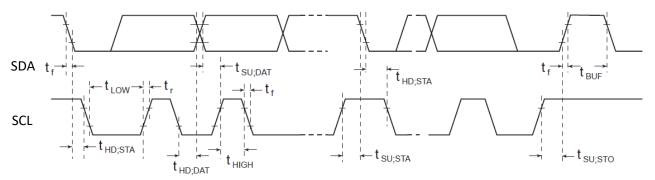


Figure 3-2 I2C Timing Sequence

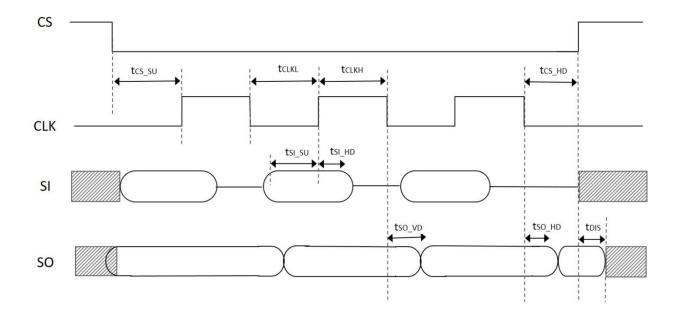
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3.6.3 SPI Characteristics

Parameter	Symbol	Min	Max	Unit
SPI Frequency	f _{SPI}		5	MHz
SPI Period	t _{SPI}	200		ns
High period of the SCLK pin	t _{CLKH}	90		ns
Low period of the SCLK pin	t _{CLKL}	90		ns
From SPICS active to first edge	t _{CS_SU}	40		ns
From last SCLK edge to SPICS inactive	t _{CS_HD}	40		ns
Time between SPI transaction	t _{CS_WA}	1		us
Data Input Setup Time	t _{si_su}	10		ns
Data Input Hold time	t _{si_HD}	10		ns
Data Output Valid Time	t _{so_VD}		80	ns
Data Output Hold Time	t _{so_HD}	0		ns

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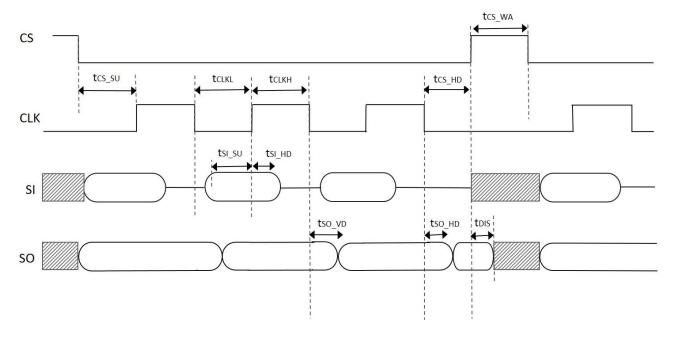


Figure 3-3 SPI Sequence

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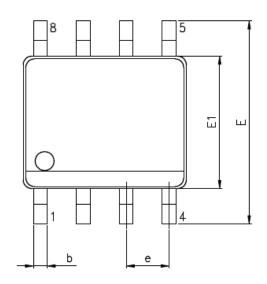
3.7 EEPROM Characteristics

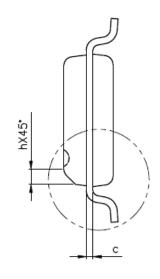
Parameter	Mln	Тур	Max	Unit
Write Endurance (Sector Endurance)	100,000	-	-	Cycles
Data Retention(at 25°C)	100	-	-	Years
Data Retention(at 85°C)	20	-	-	Years

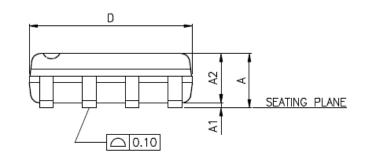
No.: TDDS01-S7101-EN(B) Name: SQ7101/SQ7103 Brief Datasheet Version: V2.2

Appendix A. Package Information

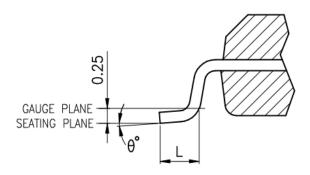
SOP8





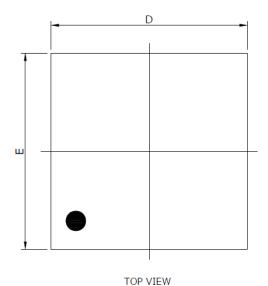


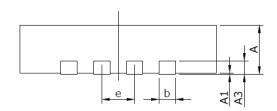
Complete	mm			
Symbol	Min.	Тур.	Max.	
Α	-	_	1.75	
A1	0.10	_	0.25	
A2	1.25	-		
b	0.31	-	0.51	
С	0.10	-	0.25	
D	4.90 BSC			
Е	6.00 BSC			
E1	3.90 BSC			
e	1.27 BSC			
L	0.40	-	1.27	
h	0.25	_	0.50	
θ	0 °	_	8°	

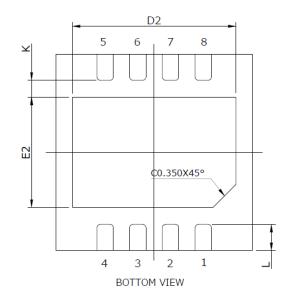


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8-Lead DFN (3mm x 3mm)







	mm			
Symbol	Min.	Тур.	Max.	
Α	0.70	0.75	0.80	
A1	0.00	0.02	0.05	
A3	0.203 REF.			
Ь	0.20	0.25	0.30	
D	2.90	3.00	3.10	
Е	2.90	3.00	3.10	
е	0.50 BSC			
L	0.35	0.40	0.45	
D2	2.45	2.50	2.55	
E2	1.63	1.68	1.73	
K	0.20	_	_	

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Appendix B. Ordering Information

When ordering products, please provide the following details:

trien ordering products) product provide the following details:				
Ordering	Product	Prov Packaging Prov	Provisioning	Description
Information	Information	i ackaging	Service	Description
				I2C, SOP8, Tape & Reel,
	SQ7101SP008C00R	Т	Y	85°C, provisioning
				service
				I2C, DFN 3x3, Tape &
SQ7101N3008C00R Example SQ7103SP008S00R	SQ7101N3008C00R	Т	N	Reel, 85°C, no
				provisioning service
				SPI, SOP8, Tape & Reel,
	SQ7103SP008S00R	Т	Y	85°C, provisioning
				service
				SPI, DFN 3x3, Tape &
	SQ7103N3008S00R	Т	N	Reel, 85°C, no
				provisioning service

Note 1: "Packaging"- T: Tape & Reel; B: Tube/Tray

Note 2: "Provisioning service for Customers" - Y: Need provisioning service for customers; N: No provisioning service for customers

iMQ Technology Inc. No.: TDDS01-S7101-EN(B) Name: SQ7101/SQ7103 Brief Datasheet Version: V2.2 Appendix C. Product Number Information Example: <u>71</u> <u>01</u> <u>800</u> <u>C</u> 00 <u>R</u> iMQ SQ product

Package Type Package Type Code SP SOP N3 DFN 3x3

Product Series -

Sub Series -

Pin Count Code Pin 800 8

Communication Interface

Code	Type.
С	I2C
S	SPI
W	SWI

Designator

Operating Temp -

Code	Operating Temp.
R	-40~85°C
X	-40~105°C

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Appendix D. Glossary

English	Description
AES	Advanced Encryption Standard
Ciphertext	Encrypted text
Cleartext	Text without encryption
MAC	Message Authentication Code
NONCE	Number of once
Plaintext	Text without encryption
Session Key	Key for one communication session
TRNG	True Random Number Generator

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Revision History

Version	Issued Date	Description
V2.2	2024/10/28	Add Appendix B. Ordering Information Add Appendix C. Product Number Information
V2.1	2024/5/24	1. Sync with datasheet V2.1 full version 2. Modify "Supply Voltage" to "Operating Voltage" in 3.2.1 Operation Conditions
V2.0	2024/03/4	1. Sync with datasheet V2.0 full version
V1.9	2023/12/26	1. Sync with datasheet V1.9 full version 2. Add SQ7103 8-Lead DFN package and pin assignment 3. Add PRODUCT info: SQ7101SP008C00R, SQ7101N3008C00R, SQ7103SP008S00R, SQ7103N3008S00R
V1.7	2023/4/20	1.Operating voltage change to 2.0~5.5V, modify "2.1 Absolute Maximum Ratings." And "2.2.1 Operation Conditions." Update "figure 2-1 Operation Timing of power-on reset" and add note. 2. "2.6.1 AC Paramenters "add note "Power-Up Ready Time does not include the executing time for BOOTROM code. The BOOTROM code executing time is around 10ms." 3."3.6.2 I2C Characteristics " update the figure of thd:DDAT Add SDA and SCL to "figure 2-2 I2C Timing Sequence."
V1.6	2023/3/30	1.Modify "CH Power-on Reset Characteristics"
V1.5	2022/7/21	1.Modify the description of small zone 2.Add package type "8L DFN 3x3" to "1.1 pin assignment/description" and "Appendix A
V1.4	2021/12/29	1.Modify "2.4 Power-on Reset Characteristics" 2. Add "CH2.5. BROR Characteristics"
V1.3	2021/6/24	 Solve DecRead issue that Param2 of command is not matched with FirstBlock.Param2. Add: "4.2 SQ7103 Pin Assignment/ Description Add: "5.4.3 SPI Characteristics" Add "CH5.5 EEPROM Characteristics" description. Add "CH 7.1 Command Introduction" description. Add "CH 7.3.13 INFO Command "selector for CountStatus. Renew "CH7.3.25 SHA Input Parameters" Mode Add "Appendix A. Package Information"